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STMicroelectronics STI13005-1

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High voltage fast-switching NPN power transistor

Preliminary data

Features

- STI13005-1 is opposite pin out versus standard IPAK package
- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed

Application

Switch mode power supplies (AC-DC converters)

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

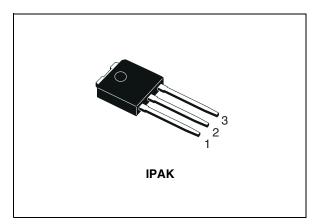


Figure 1. Internal schematic diagram

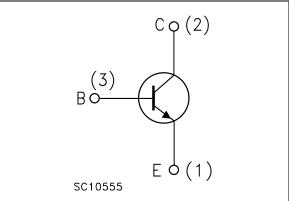


Table 1.Device summary

Order code	Marking	Package	Packaging
STI13005-1	113005	IPAK	Tube

February 2010

Doc ID 17147 Rev 1

1/10



Electrical ratings

STI13005-1

57

1 Electrical ratings

Table 2.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V _{EBO}	Emitter-base voltage ($I_C = 0$; $I_B = 1.5 A$; $t_p < 10 ms$)	V _{(BR)EBO}	V
Ι _C	Collector current	3	Α
I _{CM}	Collector peak current (t _P < 5 ms)	6	Α
Ι _Β	Base current	1.5	Α
I _{BM}	Base peak current (t _P < 5 ms)	3	Α
P _{TOT}	Total dissipation at $T_c = 25 \ ^{\circ}C$	30	W
T _{STG}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3	. Thermal	data
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Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	4.2	°C/W





2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4.						
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
1	Collector cut-off current	V _{CE} = 700 V			1	mA
ICES	(V _{BE} = 0)	$V_{CE} = 700 \text{ V}$ $T_{C} = 125 \text{ °C}$			5	mA
I _{CEO}	Collector-cut-off current $(I_B = 0)$	V _{CE} = 400 V			1	mA
V _{(BR)EBO}	Emitter base breakdown voltage $(I_{\rm C}=0)$	I _E = 10 mA	9		18	v
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA	400			v
	Collector-emitter	$I_{\rm C} = 1$ A $I_{\rm B} = 200$ mA			0.5	V
V _{CE(sat)} ⁽¹⁾	saturation voltage	$I_{\rm C} = 2A$ $I_{\rm B} = 500 \rm{mA}$			0.6	V
	outuration voltage	$I_{\rm C} = 3A$ $I_{\rm B} = 750 {\rm mA}$			5	V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation	$I_{\rm C} = 1$ A $I_{\rm B} = 200$ mA			1.2	V
♥BE(sat) `´	voltage	$I_{\rm C} = 2A$ $I_{\rm B} = 500 {\rm mA}$			1.6	V
		$I_{C} = 500 \ \mu A$ $V_{CE} = 2 \ V$	15			
h _{FF} ⁽¹⁾	DC current gain	$I_{C} = 425 \text{ mA}$ $V_{CE} = 2 \text{ V}$	24			
E	-	$I_{\rm C} = 1 {\rm A}$ $V_{\rm CE} = 5 {\rm V}$	10		30	
		$I_{\rm C} = 2 \mbox{ A}$ $V_{\rm CE} = 5 \mbox{ V}$	8		24	
	Resistive load	$I_{\rm C} = 2 {\rm A}$ $V_{\rm CC} = 125 {\rm V}$				
t _s	Storage time	$I_{B1} = -I_{B2} = 400 \text{ mA}$		1.65		μs
t _f	Fall time	t _p = 30 μs		260		ns
	Inductive load	$I_{\rm C} = 1 \ {\rm A}$ $V_{\rm clamp} = 300 \ {\rm V}$				
t _s	Storage time	$I_{B1} = 200 \text{ mA } V_{BE(off)} = -5 \text{ V}$		0.8		μs
t _f	Fall time	$L = 50 \text{ mH}$ $R_{BB} = 0$		150		ns

Table 4. Electrical characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %



Electrical characteristics

STI13005-1

DG11540

0.5A

0.4A

0.3A 0.2A

I_B=0.1A

 $V_{CE}(V)$

2.1 **Electrical characteristics (curves)**

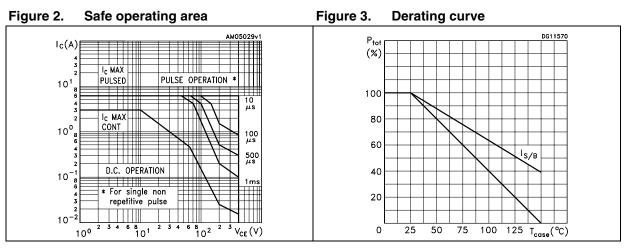


Figure 4. **Reverse biased SOA**

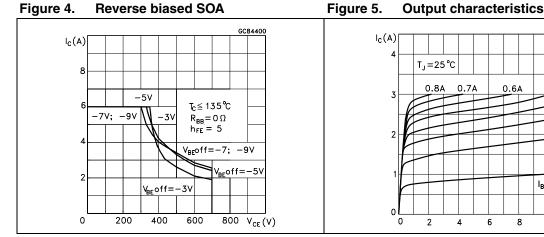
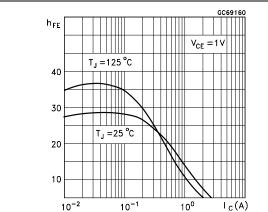


Figure 6. DC current gain (V_{CE} = 1 V)





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6

8

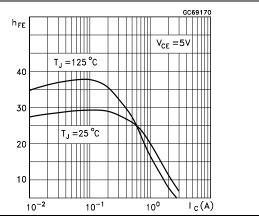
2

T_ = 25 °C

0.8A

0.7A

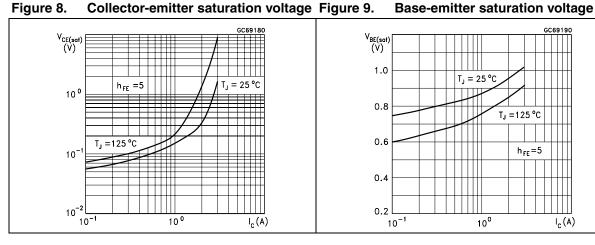
0.6A



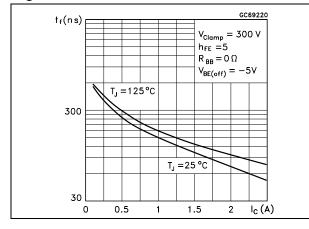




Electrical characteristics

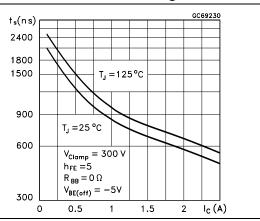












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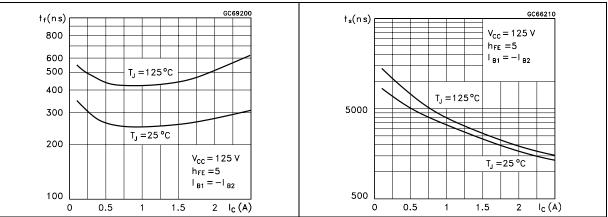
T_J = 25 °C

T_J = 125 °C

h_{FE}=5

 $I_{c}(\bar{A})$





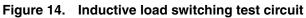
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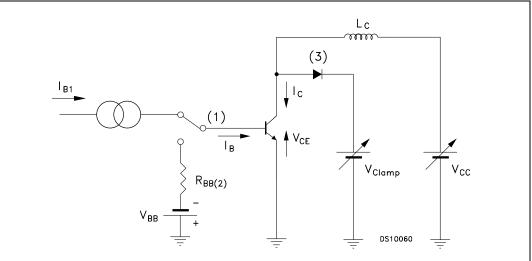


Test circuits

57

3 Test circuits

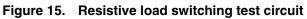


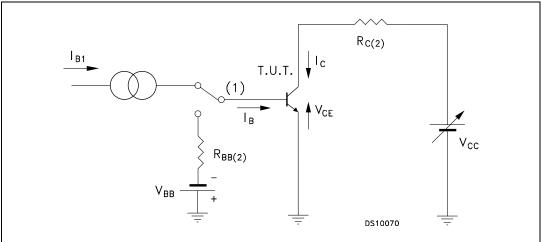


1) Fast electronic switch

2) Non-inductive resistor

3) Fast recovery rectifier





1) Fast electronic switch

2) Non-inductive resistor





Package mechanical data

4 Package mechanical data

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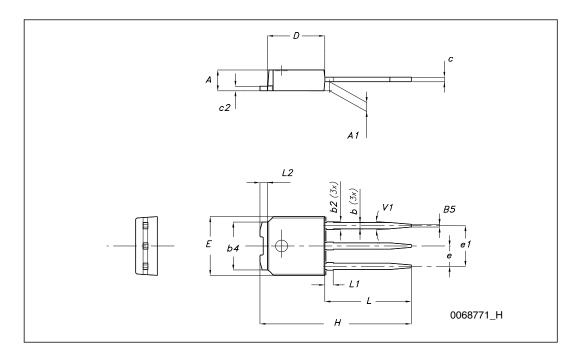


Package mechanical data

STI13005-1

57

TO-251 (IPAK) mechanical data				
DIM.		mm.		
	min.	typ	max.	
A	2.20		2.40	
A1	0.90		1.10	
b	0.64		0.90	
b2			0.95	
b4	5.20		5.40	
с	0.45		0.60	
c2	0.48		0.60	
D	6.00		6.20	
E	6.40		6.60	
е		2.28		
e1	4.40		4.60	
н		16.10		
L	9.00		9.40	
(L1)	0.80		1.20	
L2		0.80		
V1		10 °		







Revision history

5 Revision history

Table 5.Document revision history

Date	Revision	Changes
18-Feb-2010	1	First release.





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